Single and Dual Low Voltage, Rail-to-Rail Input and Output, Operational Amplifiers with Shutdown

The LMV981 Single and LMV982 Dual are low-voltage operational amplifiers which can operate on single-sided power supplies (1.8 V to 5.0 V) with rail-to-rail input and output swing. Both devices come in small state-of-the-art packages and require very low quiescent current making them ideal for battery-operated, portable applications such as notebook computers and hand-held instruments. Rail-to-Rail operation allows for optimal signal-to-noise applications plus the small packages allow for closer placement to signal sources further enhancing overall signal chain performance.

The LMV981 Single and LMV982 Dual both have a shutdown pin that can be used to disable the device and further reduce power consumption. Shutdown is implemented by driving the SHDN Pin LOW.

Features

- Specified at Single-Sided Power Supply: 1.8 V, 2.7 V, and 5 V
- Small Packages:

LMV981 in a SC-70* and uLLGA (1.5mm x 1.5mm x 0.4mm) LMV982 in a Micro10* and uQFN (1.4mm x 1.8mm x 0.6 mm)

- No Output Crossover Distortion
- Extended Industrial Temperature Range: -40°C to +125°C
- Low Quiescent Current 210 µA, max per channel
- No Output Phase–Reversal from Overdriven Input
- These are Pb-Free Devices

Typical Applications

- Notebook Computers, Portable Battery-Operated Instruments, PDA's
- Active Filters, Supply-Current Monitoring

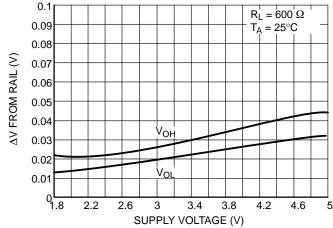


Figure 1. Output Voltage Swing vs. Supply Voltage



ON Semiconductor®

www.onsemi.com

MARKING DIAGRAMS

LMV981 (Single)



SC-70* CASE 419B





1 o V M=

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

LMV982 (Dual)



Micro10* CASE 846B





UQFN10 CASE 488AT



A = Assembly Location

Y = Year

W = Work Week

= Pb-Free Package

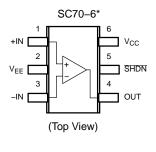
(Note: Microdot may be in either location)

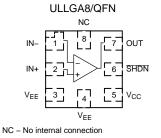
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 17 of this data sheet.

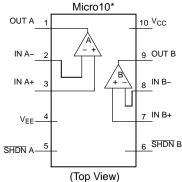
*Consult sales for package availability

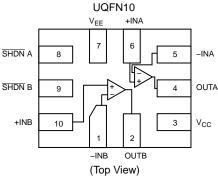
PIN CONNECTIONS





(Top View)





*Consult sales for package availability

MAXIMUM RATINGS

Symbol	Rating	Value	Unit
Vs	Supply Voltage (Operating Range V _S = 2.7 V to 5.5 V)	5.5	V
V _{IDR}	Input Differential Voltage	± Supply Voltage	V
V _{ICR}	Input Common Mode Voltage Range	-0.5 to (V+) + 0.5	V
	Maximum Input Current	10	mA
t _{So}	Output Short Circuit (Note 1)	Continuous	
TJ	Maximum Junction Temperature (Operating Range –40°C to 85°C)	150	°C
θЈА	Thermal Resistance SC-70 ULLGA8 Micro10 UQFN10	280 340 200 300	°C/W
T _{stg}	Storage Temperature (SOT23-6)	-65 to 150	°C
	Mounting Temperature (Infrared or Convection –30 sec)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ESD data available upon request.

 Continuous short–circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V+ or V- will adversely affect reliability.

1.8 V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, V^+ = 1.8 V, V^- = 0 V, V_{CM} = V+/2, V_O = V+/2 and R_L > 1 M Ω . Typical specifications represent the most likely parametric norm.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Input Offset Voltage	V_{IO}	LMV981 (Single) (-40°C to +125°C)		1	6	mV
		LMV982 (Dual) (-40°C to +125°C)		1	7.5	
Input Offset Voltage Average Drift	TCV _{IO}			5.5		μV/°C
Input Bias Current (Note 2)	I _B	−40°C to +125°C		< 1		nA
Input Offset Current (Note 2)	I _{IO}	−40°C to +125°C		< 1		nA
Supply Current	I _{CC}	In Active Mode		75	185	μΑ
(per Channel)		-40°C to +125°C			205	
		In Shutdown: LMV981 (Single)			1.0	
		-40°C to +125°C			2.0	
		In Shutdown: LMV982 (Dual)			3.5	
		-40°C to +125°C			5.0	
Common Mode	CMRR	$0 \text{ V} \leq \text{V}_{\text{CM}} \leq 0.6 \text{ V}, 1.4 \text{ V} \leq \text{V}_{\text{CM}} \leq 1.8 \text{ V}$		40		dB
Rejection Ratio		- 40°C to +125°C		40		QD
		$-0.2 \text{ V} \le \text{V}_{\text{CM}} \le 0 \text{ V}, 1.8 \text{ V} \le \text{V}_{\text{CM}} \le 2 \text{ V}$		40		
Power Supply Rejection Ratio	PSRR	$1.8 \text{ V} \le \text{V}^+ \le 5 \text{ V}, \text{V}_{\text{CM}} = 0.5 \text{ V}$	50	70		dB
		-40°C to +125°C	50			
Input Common–Mode Voltage Range	VcM	For CMRR ≥ 50 dB and T _A = 25°C	V- - 0.2	-0.2 to 2.1	V+ + 0.2	V
		For CMRR \geq 50 dB and T _A = -40° C to $+85^{\circ}$ C	V -		V ⁺	1
		For CMRR \geq 50 dB and T _A = -40° C to +125°C	V ⁻ + 0.2		V ⁺ - 0.2	
Large Signal Voltage	A _V	$R_L = 600 \Omega$ to 0.9 V, $V_O = 0.2 V$ to 1.6 V, $V_{CM} = 0.5 V$	77	101		dB
Gain LMV981 (Single) (Note 2)		-40°C to +125°C	73			
(= 3 = / (= = /		$R_L = 2 \text{ k}\Omega \text{ to } 0.9 \text{V}, \text{ V}_O = 0.2 \text{ V to } 1.6 \text{ V}, \text{ V}_{CM} = 0.5 \text{ V}$	80	105		
		-40°C to +125°C	75			
Large Signal Voltage	1	$R_L = 600 \Omega$ to 0.9 V, $V_O = 0.2 V$ to 1.6 V, $V_{CM} = 0.5 V$	75	90		
Gain LMV982 (Dual) (Note 2)		-40°C to +125°C	72			
(. 1010)		$R_L = 2 \text{ k}\Omega \text{ to } 0.9 \text{ V}, \text{ V}_O = 0.2 \text{ V to } 1.6 \text{ V}, \text{V}_{CM} = 0.5 \text{ V}$	78	100		
		-40°C to +125°C	75			
Output Swing	V _{OH}	$R_L = 600 \Omega$ to 0.9V, $V_{IN} = \pm 100 \text{ mV}$	1.65	1.72		V
		-40°C to +125°C	1.63			
	V _{OL}	$R_L = 600 \Omega$ to 0.9V, $V_{IN} = \pm 100 \text{ mV}$		0.077	0.105	
		-40°C to +125°C			0.12	
	V _{OH}	$R_L = 2 \text{ k}\Omega \text{ to } 0.9 \text{V}, \text{ V}_{\text{IN}} = \pm 100 \text{ mV}$	1.75	1.77		
	311	-40°C to +125°C	1.74			
	V _{OL}	$R_L = 2 \text{ k}\Omega \text{ to } 0.9 \text{ V}, V_{IN} = \pm 100 \text{ mV}$	<u> </u>	0.24	0.035	
		-40°C to +125°C	-		0.04	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Guaranteed by design and/or characterization.

1.8 V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, $V^+ = 1.8 \text{ V}$, $V^- = 0 \text{ V}$, $V_{CM} = V+/2$, $V_O = V^+/2$ and $R_L > 1 \text{ M}\Omega$. Typical specifications represent the most likely parametric norm.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Output Short Circuit	Ι _Ο	Sourcing, $Vo = 0 V$, $V_{IN} = +100 \text{ mV}$	4.0	30		mA
Current		−40°C to +125°C	3.3			
		Sinking, Vo = 1.8V, $V_{IN} = -100 \text{ mV}$	7.0	60		
		−40°C to +125°C	5.0			
Shutdown Enable	V _{SHDN}	Turn-on Voltage to Enable Device		1.0		V
Control		Turn-off Voltage to Shutdown Device		0.55		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Guaranteed by design and/or characterization.

1.8V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for $T_A = 25^{\circ}C$, $V_{+} = 1.8 \text{ V}$, $V_{-} = 0 \text{ V}$, $V_{CM} = 2.0 \text{ V}$, $V_{0} = V_{+}/2$ and $R_{L} > 1 \text{ M}\Omega$. Typical specifications represent the most likely parametric norm. Min/Max specifications are guaranteed by testing, characterization, or statistical analysis.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Slew Rate	SR	(Note 3)		0.35		V/μS
Gain Bandwidth Product	GBWP			1.4		MHz
Phase Margin	Θm			67		٥
Gain Margin	Gm			7		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz, V _{CM} = 0.5 V		60		nV/√ Hz
Total Harmonic Distortion	THD	f = 1 kHz, A_V = +1, R_L = 600 Ω , V_O = 1 V_{PP}		0.023		%
Amplifier–to–Amplifier Isolation		(Note 4)		123		dB

- 3. Connected as voltage follower with input step from V- to V+. Number specified is the slower of the positive and negative slew rates.
- 4. Input referred, $R_L = 100 \text{ k}\Omega$ connected to V+/2. Each amp excited in turn with 1 kHz to produce $V_O = 3 \text{ V}_{PP}$. (For Supply Voltages < 3 V, $V_O = V_P$).

2.7V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, $V^+ = 2.7$ V, $V^- = 0$ V, $V_{CM} = V + /2$, $V_{CM} = V + /2$, and $V_{CM} = V + /2$ and $V_{CM} = V + /2$, $V_{CM} = V +$

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	LMV981 (Single) (-40°C to +125°C)		1	6	mV
		LMV982 (Dual) (-40°C to +125°C)		1	7.5	
Input Offset Voltage Average Drift	TCV _{IO}			5.5		μV/°C
Input Bias Current (Note 5)	I _B	−40°C to +125°C		< 1		nA
Input Offset Current (Note 5)	I _{IO}	−40°C to +125°C		< 1		nA
Supply Current (per	I _{CC}	In Active Mode		80	190	μΑ
Channel)		−40°C to +125°C			210	
		In Shutdown: LMV981 (Single)			1.0	
		-40°C to +125°C			2.0	
		In Shutdown: LMV982 (Dual)			3.5	
	-	-40°C to +125°C			5.0	
Common Mode	CMRR	$0~\text{V} \leq \text{V}_{\text{CM}} \leq 1.5~\text{V}, 2.3~\text{V} \leq \text{V}_{\text{CM}} \leq 2.7~\text{V}$	50	70		dB
Rejection Ratio		-40°C to +125°C	50			
		$-0.2 \text{ V} \le \text{V}_{\text{CM}} \le 0 \text{ V}, 2.7 \text{ V} \le \text{V}_{\text{CM}} \le 2.9 \text{ V}$	50	70		
Power Supply Rejection Ratio	PSRR	$1.8 \text{ V} \le \text{V}^+ \le 5 \text{ V}, \text{V}_{\text{CM}} = 0.5 \text{ V}$	50	70		dB
		-40°C to +125°C	50			
Input Common–Mode Voltage Range	VcM	For CMRR \geq 50 dB and T _A = 25°C	V- - 0.2	-0.2 to 3.0	V+ + 0.2	V
		For CMRR \geq 50 dB and T _A = -40° C to $+85^{\circ}$ C	V-		V+	1
		For CMRR \geq 50 dB and T _A = -40° C to $+125^{\circ}$ C	V- + 0.2		V+ - 0.2	
Large Signal Voltage	A _V	R_L = 600 Ω to 1.35 V, V_O = 0.2 V to 2.5 V	87	104		dB
Gain LMV981 (Single) (Note 5)		-40°C to +125°C	86			
, , ,		$R_L = 2 \text{ k}\Omega$ to 1.35 V, $V_O = 0.2 \text{ V}$ to 2.5 V	92	110		
		-40°C to +125°C	91			
Large Signal Voltage	A _V	$R_L = 600 \Omega$ to 1.35 V, $V_O = 0.2 V$ to 2.5 V	78	90		
Gain LMV982 (Dual) (Note 5)		-40°C to +125°C	75			
()	-	$R_L = 2 \text{ k}\Omega$ to 1.35 V, $V_O = 0.2 \text{ V}$ to 2.5 V	81	100		
		-40°C to +125°C	78			
Output Swing	V _{OH}	$R_L = 600 \Omega$ to 1.35 V, $V_{IN} = \pm 100 \text{ mV}$	2.55	2.62		V
		-40°C to +125°C	2.53			
	V _{OL}	R_L = 600 Ω to 1.35 V, V_{IN} = ±100 mV		0.083	0.11	
	-	-40°C to +125°C			0.13	
	V _{OH}	$R_L = 2 \text{ k}\Omega \text{ to } 1.35 \text{ V}, V_{IN} = \pm 100 \text{ mV}$	2.65	2.675		
		-40°C to +125°C	2.64			
	V _{OL}	$R_L = 2 \text{ k}\Omega \text{ to } 1.35 \text{ V}, V_{IN} = \pm 100 \text{ mV}$		0.025	0.04	
	- 0L	-40°C to +125°C			0.045	1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{5.} Guaranteed by design and/or characterization.

2.7V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25$ °C, $V^+ = 2.7$ V, $V^- = 0$ V, $V_{CM} = V+/2$, $V_O = V^+/2$ and $R_L > 1$ M Ω . Typical specifications represent the most likely parametric norm.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Output Short Circuit	I _O	Sourcing, Vo = 0 V, $V_{IN} = \pm 100 \text{ mV}$	20	65		mA
Current		-40°C to +125°C	15			
		Sinking, Vo = 0 V, $V_{IN} = -100 \text{ mV}$	18	75		
		-40°C to +125°C	12			
Shutdown Enable	V _{SHDN}	Turn-on Voltage to Enable Device		1.9		V
Control		Turn-off Voltage to Shutdown Device		0.55		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Guaranteed by design and/or characterization.

2.7V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for $T_A = 25^{\circ}C$, $V_{+} = 2.7 \text{ V}$, $V_{-} = 0 \text{ V}$, $V_{CM} = 2.0 \text{ V}$, $V_{0} = V_{0} = 0 \text{ V}$, $V_{0} =$

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Slew Rate	SR	(Note 6)		0.4		V/uS
Gain Bandwidth Product	GBWP			1.4		MHz
Phase Margin	Θm			70		٥
Gain Margin	Gm			7.5		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz, V _{CM} = 1.0 V		57		nV/√ Hz
Total Harmonic Distortion	THD	f = 1 kHz, A_V = +1, R_L = 600 Ω , V_O = 1 V_{PP}		0.022		%
Amplifier-to-Amplifier Isolation		(Note 7)		123		dB

^{6.} Connected as voltage follower with input step from V- to V+. Number specified is the slower of the positive and negative slew rates.

Input referred, R_L = 100 kΩ connected to V+/2. Each amp excited in turn with 1 kHz to produce V_O = 3 V_{PP}. (For Supply Voltages < 3 V, V_O = V+).

5V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, $V^+ = 5$ V, $V^- = 0$ V, $V_{CM} = V+/2$, $V_{O} = V^+/2$ and $R_L > 1$ M Ω . Typical specifications represent the most likely parametric norm.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	LMV981 (Single) (-40°C to +125°C)		1	6	mV
		LMV982 (Dual) (-40°C to +125°C)		1	7.5	
Input Offset Voltage Average Drift	TCV _{IO}			5.5		μV/°C
Input Bias Current (Note 8)	I _B	−40°C to +125°C		< 1		nA
Input Offset Current (Note 8)	I _{IO}	−40°C to +125°C		< 1		nA
Supply Current (per	I _{CC}	In Active Mode		95	210	μΑ
Channel)		−40°C to +125°C			230	
		In Shutdown: LMV981 (Single)			1.0	
		-40°C to +125°C			2.0	
		In Shutdown: LMV982 (Dual)			3.5	
		-40°C to +125°C			5.0	
Common-Mode	CMRR	$0~\text{V} \leq \text{V}_{\text{CM}} \leq 3.8~\text{V}, 4.6~\text{V} \leq \text{V}_{\text{CM}} \leq 5.0~\text{V}$	50	70		dB
Rejection Ratio		-40°C to +125°C	50			
		$-0.2 \text{ V} \le \text{V}_{\text{CM}} \le 0 \text{ V}, 5.0 \text{ V} \le \text{V}_{\text{CM}} \le 5.2 \text{V}$	50	70		
Power Supply	PSRR	$1.8 \text{ V} \leq \text{V}^+ \leq 5 \text{ V}, \text{V}_{\text{CM}} = 0.5 \text{ V}$	50	70		dB
Rejection Ratio		-40°C to +125°C	50			
Input Common–Mode Voltage Range	Vсм	For CMRR ≥ 50 dB and $T_A = 25^{\circ}C$	V- - 0.2	-0.2 to 5.3	V+ + 0.2	V
		For CMRR \geq 50 dB and T _A = -40° C to $+85^{\circ}$ C	٧-		V+	1
		For CMRR \geq 50 dB and T _A = -40° C to $+125^{\circ}$ C	V ⁻ + 0.3		V+ - 0.3	
Large Signal Voltage	A _V	R _L = 600 Ω to 2.5 V, V _O = 0.2 V to 4.8 V	88	102		dB
Gain LMV981 (Single) (Note 8)		-40°C to +125°C	87			
, , , ,		R_L = 2 k Ω to 2.5 V, V_O = 0.2 V to 4.8 V	94	113		
		-40°C to +125°C	93			
Large Signal Voltage	A _V	R_L = 600 Ω to 2.5 V, V_O = 0.2 V to 4.8 V	81	90		
Gain LMV982 (Dual) (Note 8)		-40°C to +125°C	78			
,		R_L = 2 k Ω to 2.5 V, V_O = 0.2 V to 4.8 V	85	100		
		-40°C to +125°C	82			
Output Swing	V _{OH}	R_L = 600 Ω to 2.5 V, V_{IN} = \pm 100 mV	4.855	4.89		V
		-40°C to +125°C	4.835			
	V _{OL}	R _L = 600 Ω to 2.5 V, V _{IN} = \pm 100 mV	1	0.12	0.16	- - -
		-40°C to +125°C	1		0.18	
	V _{OH}	R_L = 2 k Ω to 2.5 V, V_{IN} = \pm 100 mV	4.945	4.967		
		-40°C to +125°C	4.935			
	V _{OL}	R_L = 2 k Ω to 2.5 V, V_{IN} = \pm 100 mV		0.037	0.065	
		-40°C to +125°C	1	<u> </u>	0.075	1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{8.} Guaranteed by design and/or characterization.

5V DC ELECTRICAL CHARACTERISTICS Unless otherwise noted, all min/max limits are guaranteed for $T_A = 25^{\circ}C$, $V^+ = 5$ V, $V^- = 0$ V, $V_{CM} = V+/2$, $V_{CM} = V+/2$ and $R_L > 1$ M Ω . Typical specifications represent the most likely parametric norm.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Output Short-Circuit	I _O	Sourcing, Vo = 0 V, V _{IN} = +100 mV	40	60		mA
Current		-40°C to +125°C	40			
		Sinking, Vo = 5 V, $V_{IN} = -100 \text{ mV}$	45	65		
		-40°C to +125°C	45			
Shutdown Enable	V _{SHDN}	Turn-on Voltage to Enable Device		4.2		V
Control		Turn-off Voltage to Shutdown Device		0.55		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

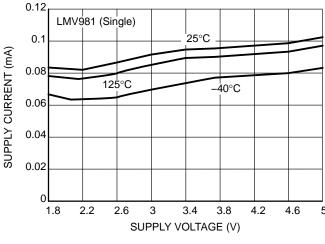
8. Guaranteed by design and/or characterization.

5V AC ELECTRICAL CHARACTERISTICS Unless otherwise specified, all limits are guaranteed for $T_A = 25$ °C, $V_T = 5$ V, $V_T = 0$ V,

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Slew Rate	SR	(Note 9)		0.48		V/uS
Gain Bandwidth Product	GBWP			1.5		MHz
Phase Margin	Θm			65		٥
Gain Margin	Gm			8		dB
Input-Referred Voltage Noise	e _n	f = 50 kHz, V _{CM} = 2 V		50		nV/√ Hz
Total Harmonic Distortion	THD	f = 1 kHz, A_V = +1, R_L = 600 Ω , V_O = 1 V_{PP}		0.022		%
Amplifier-to- Amplifier Isolation		(Note 10)		123		dB

Connected as voltage follower with input step from V- to V+. Number specified is the slower of the positive and negative slew rates.
 Input referred, R_L = 100 kΩ connected to V+/2. Each amp excited in turn with 1 kHz to produce V_O = 3 V_{PP}. (For Supply Voltages < 3 V, V_O = V+).

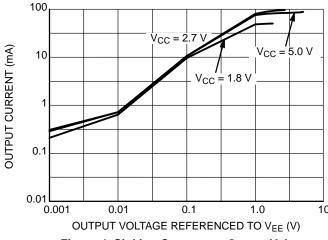
TYPICAL CHARACTERISTICS



100 V_{CC} = 5.0 V V_{CC} = 5.0 V V_{CC} = 1.8 V 0.01 0.01 0.01 0.1 1.0 10 OUTPUT VOLTAGE REFERENCED TO V_{CC} (V)

Figure 2. Supply Current vs. Supply Voltage

Figure 3. Sourcing Current vs. Output Voltage $(T_A = 25^{\circ}C)$



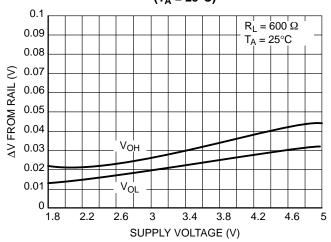


Figure 4. Sinking Current vs. Output Voltage $(T_A = 25^{\circ}C)$

Figure 5. Output Voltage Swing vs. Supply Voltage

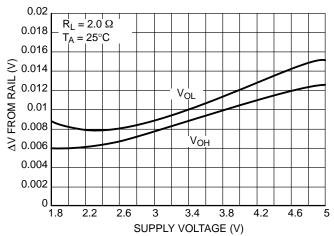


Figure 6. Output Voltage vs. Supply Voltage

TYPICAL CHARACTERISTICS

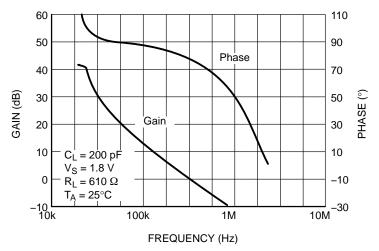


Figure 7. Gain and Phase vs. Frequency

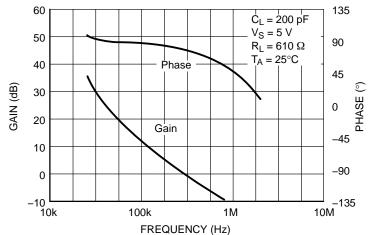


Figure 8. Gain and Phase vs. Frequency

TYPICAL CHARACTERISTICS

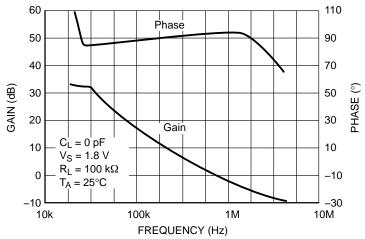


Figure 9. Gain and Phase vs. Frequency

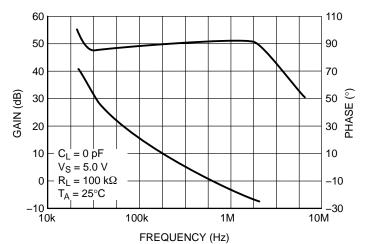


Figure 10. Gain and Phase vs. Frequency

TYPICAL CHARACTERISTICS

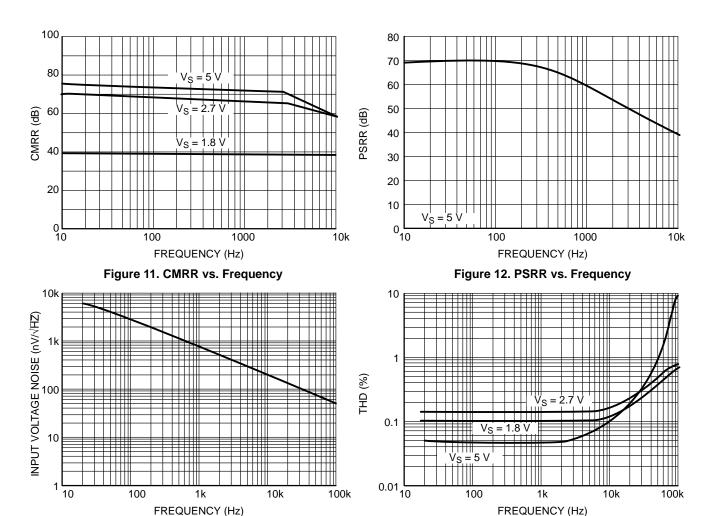


Figure 13. Input Voltage Noise vs. Frequency

Figure 14. THD vs. Frequency

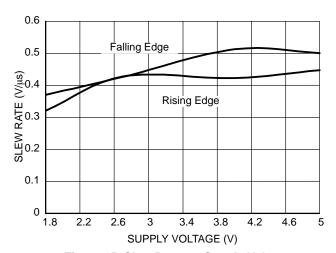


Figure 15. Slew Rate vs. Supply Voltage

TYPICAL CHARACTERISTICS



TIME (2µs/div)

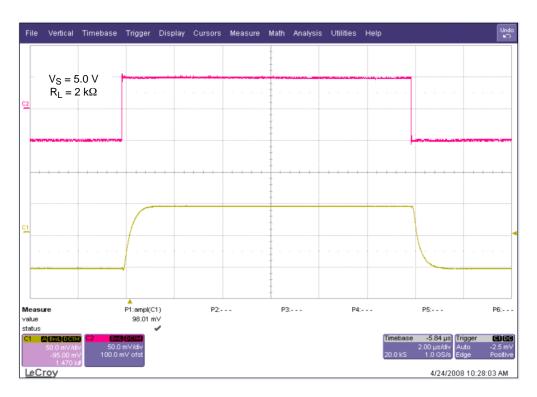
Figure 16. Small Signal Noninverting Response



TIME (2µs/div)

Figure 17. Small Signal Noninverting Response

TYPICAL CHARACTERISTICS



TIME (2µs/div)

Figure 18. Small Signal Noninverting Response



TIME (2µs/div)

Figure 19. Large Signal Noninverting Response

TYPICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ and } V_S = 5 \text{ V unless otherwise specified})$



TIME (2µs/div)

Figure 20. Large Signal Noninverting Response



TIME (2µs/div)

Figure 21. Large Signal Noninverting Response

TYPICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ and } V_S = 5 \text{ V unless otherwise specified})$

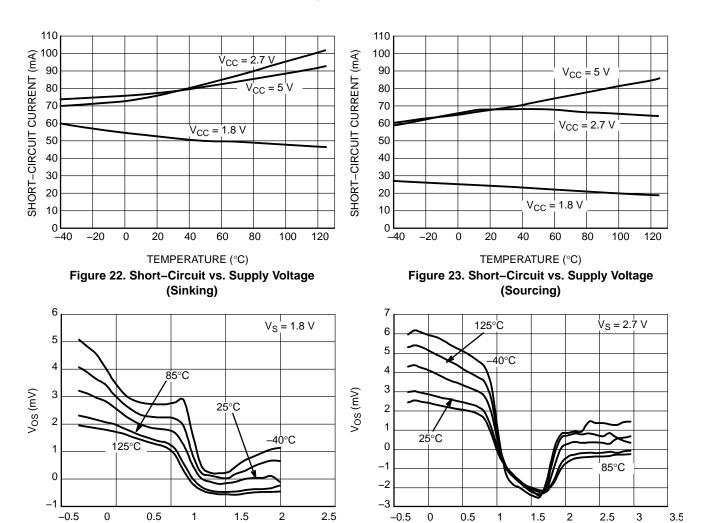


Figure 24. Offset Voltage vs. Common Mode Range V_{DD} 1.8 V

V_{CM} (V)

 $\begin{array}{c} V_{\text{CM}}\left(\text{V}\right) \\ \text{Figure 25. Offset Voltage vs. Common Mode} \\ \text{Range V}_{\text{DD}} \text{ 2.7 V} \end{array}$

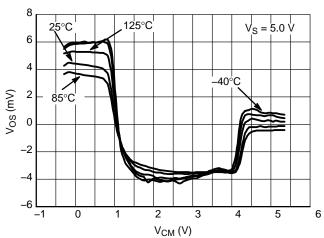


Figure 26. Offset Voltage vs. Common Mode Range V_{DD} 5.0 V

APPLICATION INFORMATION

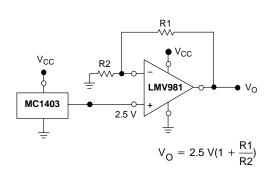


Figure 27. Voltage Reference

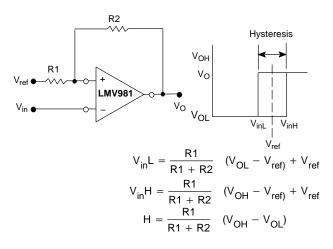


Figure 29. Comparator with Hysteresis

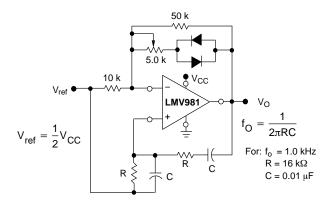
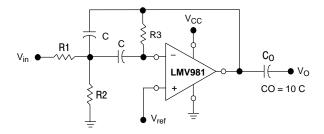


Figure 28. Wien Bridge Oscillator



Given: f_0 = center frequency $A(f_0)$ = gain at center frequency

Choose value f_0 , CThen: $R3 = \frac{Q}{\pi f_0 C}$ $R1 = \frac{R3}{2 A(f_0)}$ $R2 = \frac{R1 R3}{4Q^2 R1 - R3}$

For less than 10% error from operational amplifier, (($Q_O f_O$)/BW) < 0.1 where f_o and BW are expressed in Hz. If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 30. Multiple Feedback Bandpass Filter

ORDERING INFORMATION

Order Number	# of Channels	Specific Device Marking	Package Type	Shipping [†]
LMV981SQ3T2G*	Single	AAE	SC70-6* (Pb-Free)	3000 / Tape & Reel
LMV981MU3TBG	Single	V	ULLGA8 (Pb-Free)	3000 / Tape & Reel
LMV982DMR2G*	Dual	V982	Micro10* (Pb-Free)	4000 / Tape & Reel
LMV982MUTAG	Dual	DE	UQFN10 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}Consult sales for package availability.

D

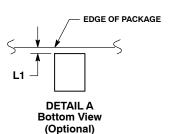
PIN 1 REFERENCE

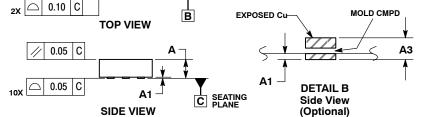
0.10 C

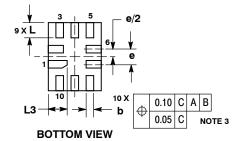


Α

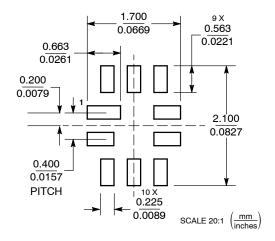
DATE 01 AUG 2007







MOUNTING FOOTPRINT



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM
- FROM TERMINAL.

 COPLANARITY APPLIES TO THE EXPOSED PAD
 AS WELL AS THE TERMINALS.

	MILLIMETERS				
DIM	MIN	MAX			
Α	0.45	0.60			
A1	0.00	0.05			
A3	0.127	REF			
b	0.15	0.25			
D	1.40	BSC			
E	1.80	BSC			
е	0.40	BSC			
L	0.30	0.50			
L1	0.00	0.15			
L3	0.40	0.60			

GENERIC MARKING DIAGRAM*



XX = Specific Device Code

= Date Code М = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

DOCUMENT NUMBER:	98AON22493D	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED	, ,
DESCRIPTION:	10 PIN UQFN, 1.4 X 1.8, 0.4P		PAGE 1 OF 1

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